

# FAST DMOS FET Switches

## N-Channel Enhancement-Mode



### SST211 / SST213 / SST215

#### FEATURES

- High Speed Switching.....  $t_d(ON)$  1ns
- Low Capacitance ..... 2.4pF typical
- Low ON Resistance..... 50 $\Omega$  typical
- High Gain
- Surface Mount Package

#### APPLICATIONS

- Ultra High Speed Analog Switching
- Sample and Hold
- Multiplexers
- High Gain Amplifiers

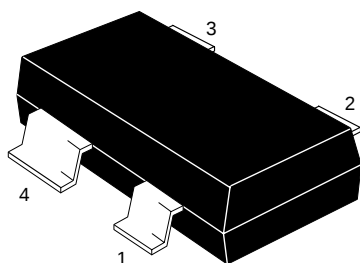
#### DESCRIPTION

Designed for audio, video and high frequency applications, the SST211 Series is a high speed, ultra low capacitance SPST analog switch. Utilizing Calogic's proprietary DMOS processing the SST211 Series features an integrated zener diode designed to protect the gate from electrical over stress.

#### ORDERING INFORMATION

| Part    | Package                  | Temperature Range |
|---------|--------------------------|-------------------|
| SST211  | SOT-143 Surface Mount    | -55°C to +125°C   |
| SST213  | SOT-143 Surface Mount    | -55°C to +125°C   |
| SST215  | SOT-143 Surface Mount    | -55°C to +125°C   |
| XSST211 | Sorted Chips in Carriers | -55°C to +125°C   |
| XSST213 | Sorted Chips in Carriers | -55°C to +125°C   |
| XSST215 | Sorted Chips in Carriers | -55°C to +125°C   |

#### PIN CONFIGURATION

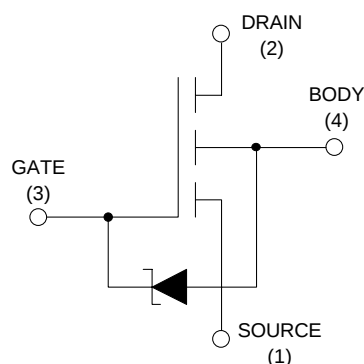


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#### PRODUCT MARKING

| SST211 | 211 |
|--------|-----|
| SST213 | 213 |
| SST215 | 215 |

#### SCHEMATIC DIAGRAM





## ABSOLUTE MAXIMUM RATINGS (T<sub>c</sub> = +25°C unless otherwise noted)

| Parameter                 | SST211 | SST213 | SST215 | Unit |
|---------------------------|--------|--------|--------|------|
| <b>Breakdown Voltages</b> |        |        |        |      |
| V <sub>DS</sub>           | +30    | +10    | +20    | V    |
| V <sub>SD</sub>           | +10    | +10    | +20    | V    |
| V <sub>DB</sub>           | +30    | +15    | +25    | V    |
| V <sub>SB</sub>           | +15    | +15    | +25    | V    |
| V <sub>GS</sub>           | -15    | -15    | -25    | V    |
|                           | +25    | +25    | +30    | V    |
| V <sub>GB</sub>           | -0.3   | -0.3   | -0.3   | V    |
|                           | +25    | +25    | +30    | V    |
| V <sub>GD</sub>           | -30    | -15    | -25    | V    |
|                           | +25    | +25    | +30    | V    |

I<sub>D</sub> Continous Drain Current . . . . . 50mA  
 P<sub>T</sub> Power Dissipation (at or below T<sub>c</sub> = +25°C) . . . 360mW  
 Linear Derating Factor 3.6mW/°C  
 T<sub>j</sub> Operating Junction Temperature Range . . -55 to +125°C  
 T<sub>S</sub> Storage Temperature Range . . . . . -55 to +150°C

## ELECTRICAL CHARACTERISTICS (T<sub>c</sub> = +25°C unless otherwise noted)

| SYMBOL          | CHARACTERISTICS                              | SST211 |     |     | SST213 |     |     | SST215 |     |     | UNIT | TEST CONDITIONS                             |                 |
|-----------------|----------------------------------------------|--------|-----|-----|--------|-----|-----|--------|-----|-----|------|---------------------------------------------|-----------------|
|                 |                                              | MIN    | TYP | MAX | MIN    | TYP | MAX | MIN    | TYP | MAX |      |                                             |                 |
| STATIC          |                                              |        |     |     |        |     |     |        |     |     |      |                                             |                 |
| BVDS            | Drain-Source Breakdown Voltage               | 30     | 35  |     |        |     |     |        |     |     | V    | ID = 10μA, VGS = VBS = 0                    |                 |
|                 |                                              | 10     | 25  |     | 10     | 25  |     | 20     | 25  |     |      | ID = 10nA, VGS = VBS = -5V                  |                 |
| BVSD            | Source-Drain Breakdown Voltage               | 10     |     |     | 10     |     |     | 20     |     |     |      | IS = 10nA, VGD = VBD = -5V                  |                 |
| BVDB            | Drain-Body Breakdown Voltage                 | 15     |     |     | 15     |     |     | 25     |     |     |      | ID = 10nA, VGB = 0 Source OPEN              |                 |
| BVSB            | Source-Body Breakdown Voltage                | 15     |     |     | 15     |     |     | 25     |     |     |      | IS = 10μA, VGB = 0 Drain OPEN               |                 |
| ID(OFF)         | Drain-Source OFF Current                     |        | 0.2 | 10  |        | 0.2 | 10  |        |     |     | nA   | VDS = 10V                                   | VGS = VBS = -5V |
|                 |                                              |        |     |     |        |     |     |        | 0.2 | 10  |      | VDS = 20V                                   |                 |
| IS(OFF)         | Source-Drain OFF Current                     |        | 0.6 | 10  |        | 0.6 | 10  |        |     |     |      | VSD = 10V                                   | VGD = VBD = -5V |
|                 |                                              |        |     |     |        |     |     |        | 0.6 | 10  |      | VSD = 20V                                   |                 |
| IGBS            | Gate-Body Leakage Current                    |        |     | 10  |        |     | 10  |        |     |     | μA   | VGB = 25V                                   | VDB = VSB = 0   |
|                 |                                              |        |     |     |        |     |     |        |     | 10  |      | VGB = 30V                                   |                 |
| VGS(th)         | Gate Threshold Voltage                       | 0.5    | 1.0 | 2.0 | 0.1    |     | 2.0 | 0.1    | 1.0 | 2.0 | V    | VDS = VGS, ID = 1μA, VSB = 0                |                 |
| rds(on)         | Drain-Source <sup>1</sup> ON Resistance      |        | 50  | 70  |        | 50  | 70  |        | 50  | 70  | ohms | VGS = 5V                                    | ID = 1mA        |
|                 |                                              |        | 30  | 45  |        | 30  | 45  |        | 30  | 45  |      | VGS = 10V                                   | VSB = 0         |
| DYNAMIC         |                                              |        |     |     |        |     |     |        |     |     |      |                                             |                 |
| gfs             | Common-Source <sup>1</sup> Foward Transcond. | 10     | 12  |     | 10     | 12  |     | 10     | 12  |     | mS   | VDS = 10V, ID = 20mA<br>f = 1KHz, VSB = 0   |                 |
| C(gS + gD + gB) | Gate Node Capacitance                        |        | 2.4 | 3.5 |        | 2.4 | 3.5 |        | 2.4 | 3.5 | pF   | VDS = 10V<br>VGS = VBS = -15V<br>f = 1MHz   |                 |
| C(gD + dB)      | Drain Node Capacitance                       |        | 1.3 | 1.5 |        | 1.3 | 1.5 |        | 1.3 | 1.5 |      |                                             |                 |
| C(gS + sB)      | Source Node Capacitance                      |        | 3.5 | 4.0 |        | 3.5 | 4.0 |        | 3.5 | 4.0 |      |                                             |                 |
| C(dg)           | Reverse Transfer Capacitance                 |        | 0.3 | 0.5 |        | 0.3 | 0.5 |        | 0.3 | 0.5 |      |                                             |                 |
| tD(ON)          | Turn ON Delay Time                           |        | 0.7 | 1.0 |        | 0.7 | 1.0 |        | 0.7 | 1.0 | ns   | VDD = 5V, VG(ON) = 10V<br>RL = 680, RG = 51 |                 |
| tr              | Rise Time                                    |        | 0.8 | 1.0 |        | 0.8 | 1.0 |        | 0.8 | 1.0 |      |                                             |                 |
| t(OFF)          | Turn OFF Time                                |        | 10  |     |        | 10  |     |        | 10  |     |      |                                             |                 |

NOTE 1: Pulse Test, 80 Sec, 1% Duty Cycle  
 Typical Performance Characteristics: See SD211-215 Series